



AP7361E

#### 1A LOW DROPOUT ADJUSTABLE AND FIXED-MODE REGULATOR WITH ENABLE & PG

### **Description**

The AP7361E is a 1A, adjustable and fixed output voltage, ultra-low dropout linear regulator with enable. The device includes pass element, error amplifier, band-gap reference, current limit and thermal shutdown circuitry. The device is turned on when EN pin is set to logic high level.

The characteristics of the low dropout voltage and low quiescent current make it suitable for low to medium power applications, for example, laptop computers, audio and video applications and battery powered devices. The typical quiescent current is approximately  $60\mu A$ . Built-in current-limit, thermal-shutdown and power good functions prevent IC from damage in fault conditions.

The AP7361E is available in U-DFN3030-8 (Type E) package.

## **Pin Assignments**

#### 

**GND** 

U-DFN3030-8 (Type E)

EN

#### **Features**

- Wide Input Voltage Range: 2.2V to 6.0V
- Output Voltage Accuracy: ±1%
- Very Low Dropout Voltage (3.3V): 360mV at 1A Typical
- Low Quiescent Current (IQ): 60µA Typical
- Adjustable Output Voltage Range: 0.8V to 5.0V
- Fixed Output Options: 1.0V, 1.2V, 1.5V, 1.8V, 2.5V, 2.8V and 3.3V
- High PSRR: 75dB @ 1kHz
- Current Limit: 1.5A
- Fold-Back Short Circuit Protection: 400mA
- Power-Good (PG) Output for Supply Monitoring and for Sequencing of Other Supplies
- Thermal Shutdown Protection
- Stable with MLCC, E-Cap, Tan-Cap or Solid Capacitor ≥ 2.2μF
- Ambient Temperature Range: -40°C to +85°C
- Available in "Green" Molding Compound (No Br, Sb)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

### **Applications**

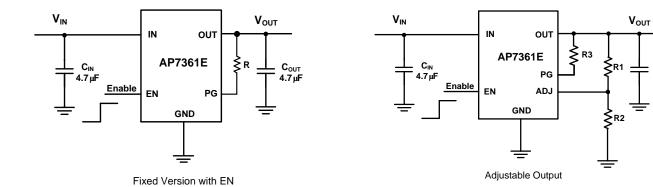
- LCD-TV, Monitor
- Set-Top-Box
- Home Electrical Appliances

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



# **Typical Applications Circuit**



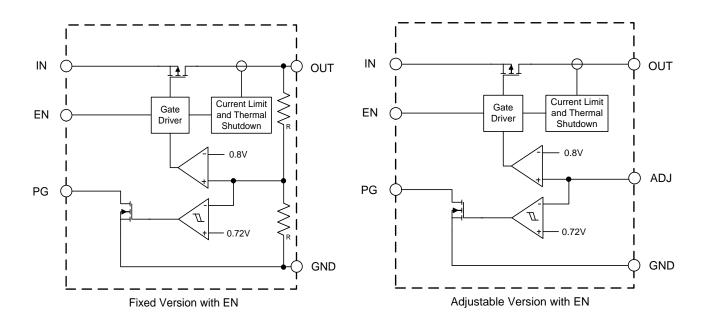
## **Pin Descriptions**

Pin Number U-DFN3030-8 (Type E)	Pin Name	Function
1	OUT	The output of the regulator. Bypass to ground through at least 2.2µF ceramic capacitor. For improved AC load response a larger capacitor is recommended.
2, 6	NC	No connection
3	ADJ/NC	Adjustable voltage version only – a resistor divider from this pin to the OUT pin and ground sets the output voltage.
4	GND	Ground
5	EN	Enable input, active high
7	PG	Power-Good pin, open-drain output. When the V <sub>OUT</sub> is below the PG threshold the PG pin is driven low; when the V <sub>OUT</sub> exceeds the threshold, the PG pin goes into a high-impedance state. To use the PG pin, use a $10k\Omega$ to $1M\Omega$ pull-up resistor to pull it up to a supply of up to 6V, which can be higher than the input voltage.
8	IN	The input of the regulator. Bypass to ground through at least 1µF ceramic capacitor.

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## **Functional Block Diagram**



## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.) (Note 4)

Symbol	Parameter	Parameter		Unit
Vin	Input Voltage		6.5	V
_	OUT, ADJ, EN Voltage	EN Voltage V <sub>IN</sub> + 0.3		V
TJ	Operating Junction Temperature Range		-40 to +150	°C
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
PD	Power Dissipation		Internally limited by maximum junction temperature of +150°C	_
PD	Power Dissipation U-DFN3030-8 (Type E)		1700	mW
ESD HBM	Human Body Model ESD Protection		> 2	kV
ESD CDM	Charge Device Model		±500	V

Note:

## Recommended Operating Conditions (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
Vin	Input Voltage	2.2	6.0	V
Vout	Output Voltage	0.8	5.0	V
lout	Output Current (Note 5)	0	1.0	Α
T <sub>A</sub>	Operating Ambient Temperature	-40	+85	°C

Note: 5. The device maintains a stable, regulated output voltage without a load current. When the output current is large, attention should be given to the limitation of the package power dissipation.

<sup>4.</sup> Stresses greater than the *Absolute Maximum Ratings* specified above can cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability can be affected by exposure to absolute maximum rating conditions for extended periods of time.



## $\textbf{Electrical Characteristics} \ (@T_A = +25 ^{\circ}\text{C}, \ V_{IN} = V_{OUT} + 1 \text{V}, \ C_{IN} = 4.7 \mu\text{F}, \ C_{OUT} = 4.7 \mu\text{F}, \ V_{EN} = V_{IN}, \ unless \ otherwise \ specified.)$

Symbol	Parameter	Test Conditions		Min	Тур	Max	Unit
V <sub>REF</sub>	FB Reference Voltage, ADJ Pin	I <sub>OUT</sub> = 10mA, T <sub>A</sub> = +25°C		0.792	0.8	0.808	V
I <sub>ADJ</sub>	ADJ Pin Leakage Current	_		_	0.1	0.5	μA
IQ	Input Quiescent Current	Enabled, I <sub>OUT</sub> = 0A		_	68	91	μA
I <sub>SHDN</sub>	Input Shutdown Current	$V_{EN} = 0V$ , $I_{OUT} = 0A$		-1	0.05	1	μA
ISHDIN	Inpat chatacini cancin		1.0V ≤ V <sub>OUT</sub> < 1.5V	V <sub>OUT</sub> (s)-	Vout(s)	V <sub>OUT</sub> (s)+ 0.015	μ/ (
Vouт	Output Voltage Accuracy	I <sub>OUT</sub> = 100mA, T <sub>A</sub> = +25°C	1.5V ≤ V <sub>OUT</sub> ≤ 3.3V	V <sub>OUT</sub> (s)*	Vout(s)	V <sub>OUT</sub> (s)*	V
ΔV оυт		\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	T <sub>A</sub> = +25°C	— —	0.01	0.1	
$\frac{\Delta V_{\text{IN}} \times V_{\text{OUT}}}{\Delta V_{\text{IN}} \times V_{\text{OUT}}}$	Line Regulation	$V_{IN} = V_{OUT} + 1V$ to 5.5V, $I_{OUT} = 100$ mA	-40°C ≤ T <sub>A</sub> ≤ +85°C	_		0.2	%/V
	Load Danidation		1.2V < V <sub>OUT</sub> ≤ 3.3V	-1.0	_	1.0	%
$\Delta V$ оит / $V$ оит	Load Regulation	IOUT from 1.0mA to 1A	1.0V ≤ V <sub>OUT</sub> ≤ 1.2V	-1.5	_	1.5	%
			1.0V ≤ V <sub>OUT</sub> < 1.1V	_	710	750	
			1.1V ≤ V <sub>OUT</sub> < 1.2V	_	600	640	
			1.2V ≤ V <sub>OUT</sub> < 1.3V	_	500	540	
		I <sub>OUT</sub> = 300mA	1.3V ≤ V <sub>OUT</sub> < 1.4V	_	400	440	
			1.4V ≤ V <sub>OUT</sub> < 1.5V	_	300	340	
			1.5V ≤ V <sub>OUT</sub> < 2.6V	_	200	250	
			2.6V ≤ V <sub>OUT</sub> ≤ 3.3V	_	90	140	
VDROPOUT	Dropout Voltage (Note 6)		1.0V ≤ V <sub>OUT</sub> < 1.1V	_	840	_	mV
V DROPOUT	Disposit Voltage (Note 5)		1.1V ≤ V <sub>OUT</sub> < 1.2V	_	780	_	
		Iout = 1A	$1.2V \le V_{OUT} < 1.3V$	_	710	_	
			1.3V ≤ V <sub>OUT</sub> < 1.4V	_	660	_	
			$1.4V \le V_{OUT} < 1.5V$	_	610	_	
			$1.5V \le V_{OUT} < 2.0V$	_	570	_	
			$2.0V \le V_{OUT} < 2.6V$		440		
			2.6V ≤ V <sub>OUT</sub> ≤ 3.3V	_	340	_	
to	Output Voltage Turn On Delay Time	VIN = VOUT + 1V, VEN High to VOUT Rising 10%		_	50	_	μs
tss	Output Voltage Ramp Up Time	Vout Rising 10% to 90%	<u> </u>	_	200	_	μs
tpg	PG React Time	Vout 90% to PG Active		_	30	_	μs
		ADJ Falling to PG Low					
tpgF	PG Off Deglitch Time	EN Goes Low to PG Low	ı	_	3	_	μs
Vpgr	PG Rising Threshold	ADJ Rising		89	92	95	%
Vpgf	PG Falling Threshold	ADJ Falling		79	82	85	%
Vpgs	PG Sinking Voltage	V <sub>IN</sub> = 3.3V, Sinking Current = 5mA		_	_	0.4	V
VIL	EN Input Logic Low Voltage	_		0	_	0.3	V
Vih	EN Input Logic High Voltage	_		1.0	_	VIN	V
RENPD	EN Pull-Down Resistor	_		_	3.0	_	ΜΩ
IEN	EN Input Leakage Current	VIN = 5.5V, VEN = 0V		-0.1	_	0.1	μΑ
R <sub>PD</sub>	Output Discharge Resistor	VoL = 1V		_	100	_	Ω
Іоит	Maximum Output Current	VIN = VOUT + 1V		1.0	_	_	Α
I <sub>LIMIT</sub>	Current Limit	V <sub>IN</sub> = V <sub>OUT</sub> + 1V (V <sub>IN MINI</sub> = 2.2V)		1.3	1.5	_	Α
I <sub>SHORT</sub>	Short-Circuit Current	$V_{IN} = V_{OUT} + 1V$ , Output	Voltage < 15% V <sub>OUT</sub>	_	400	_	mA
PSRR	Power Supply Rejection Ratio	f = 1kHz, I <sub>OUT</sub> = 100mA, V <sub>OUT</sub> = 1.2V		_	75	_	۲D
FORK	(Note 7)	f = 10kHz, I <sub>OUT</sub> = 100mA, V <sub>OUT</sub> = 1.2V		_	55	_	dB



### $\textbf{Electrical Characteristics} \ \ (@T_A = +25^{\circ}C, \ V_{IN} = V_{OUT} + 1V, \ C_{IN} = 4.7 \mu F, \ C_{OUT} = 4.7 \mu F, \ V_{EN} = V_{IN}, \ unless \ otherwise \ specified.)$ (continued)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
tsт	Start-Up Time	Vout = 3V, Cout = $2.2\mu$ F, RL = $30\Omega$	1	150		μs
$\frac{\Delta V_{\text{OUT}}}{\Delta T_{\text{A}} \times V_{\text{OUT}}}$	Output Voltage Temperature Coefficient	I <sub>OUT</sub> = 100mA, -40°C ≤ T <sub>A</sub> ≤ +85°C	_	±100	_	ppm/°C
T <sub>SHDN</sub>	Thermal Shutdown Threshold	_	_	+150	_	°C
THYS	Thermal Shutdown Hysteresis	_	_	+20	_	°C
θја	Thermal Resistance Junction-to- Ambient	U-DFN3030-8 (Type E ) (Note 8)	_	70		°C/W

Notes:

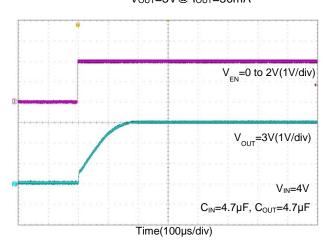
<sup>6.</sup> Dropout voltage is the voltage difference between the input and the output at which the output voltage drops 2% below its nominal value. This parameter only applies to output voltages above 1.2V since minimum  $V_{IN} = 2.2V$ .

For V<sub>IN</sub> ≥ 2.5V and V<sub>IN</sub> = V<sub>OUT</sub> +1V. For V<sub>IN</sub> < 2.5V, the PSRR performance may be reduced.</li>
 Test condition: U-DFN3030-8 (Type E) device is mounted on 2" × 2", FR-4 substrate PCB, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane.

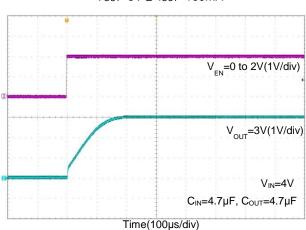


# **Typical Characteristics**

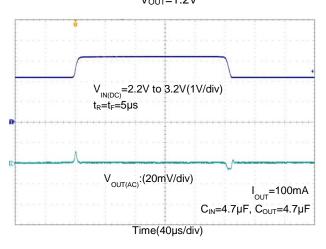




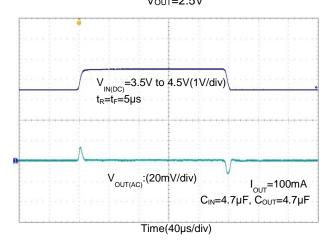
## Start-up Time Vout=3V@ Iout=100mA



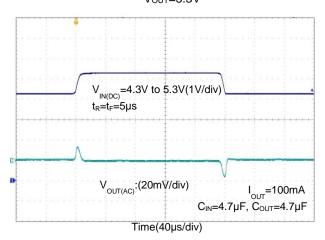
# Line Transient Response $V_{OUT}=1.2V$



Line Transient Response

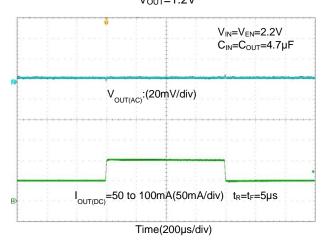


# Line Transient Response $V_{OUT=3.3V}$

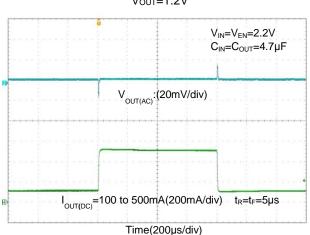




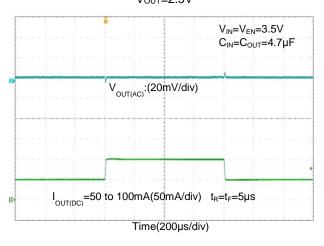
# Load Transient Response Vout=1.2V



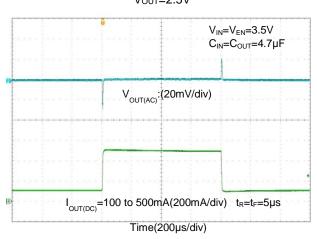
# Load Transient Response Vout=1.2V



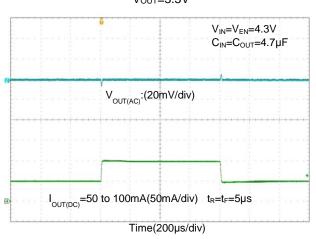
# Load Transient Response Vout=2.5V



# Load Transient Response Vout=2.5V

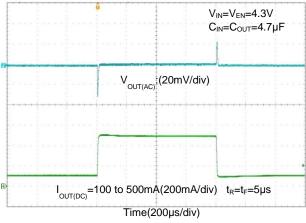


# Load Transient Response Vout=3.3V



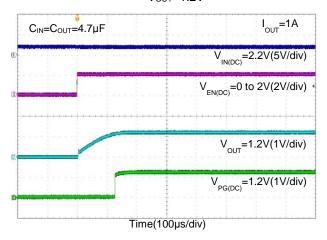
# Load Transient Response Vout=3.3V



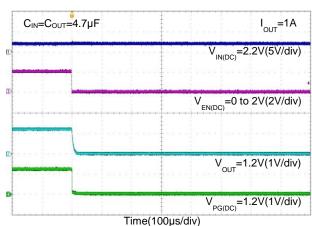




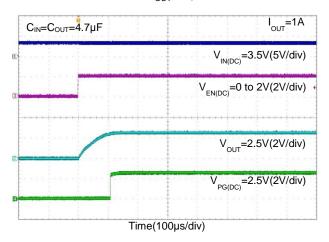
# Enable Turn-On Response Vout=1.2V



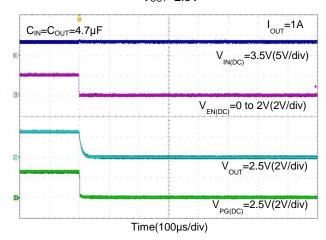
# Enable Turn-Off Response $V_{OUT}=1.2V$



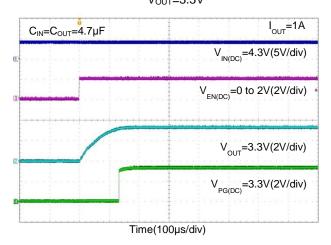
# Enable Turn-On Response $V_{OUT}=2.5V$



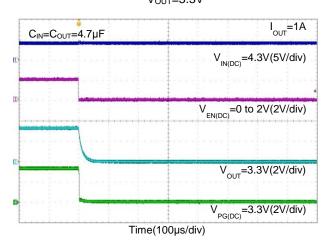
# Enable Turn-Off Response Vout=2.5V



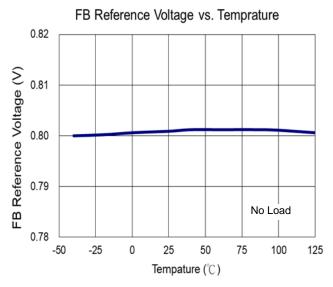
# Enable Turn-On Response $V_{OUT}=3.3V$

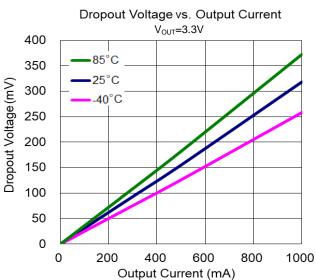


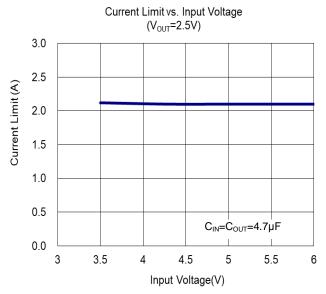
# Enable Turn-Off Response Vout=3.3V

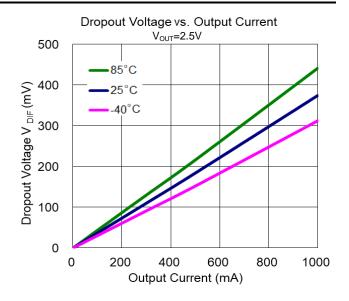


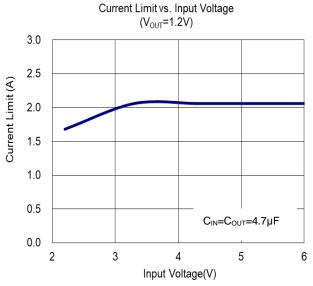


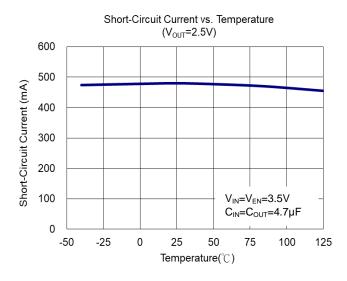




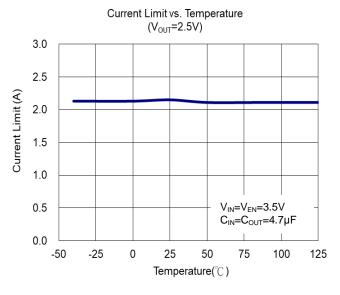


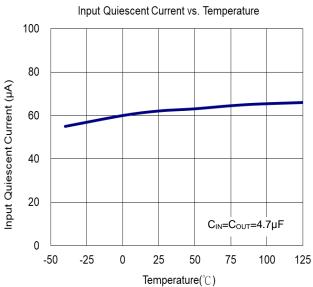


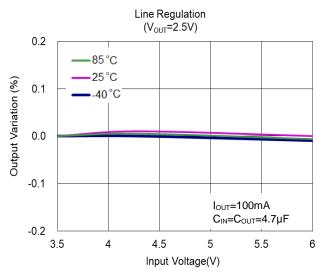


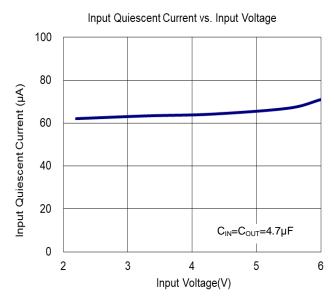


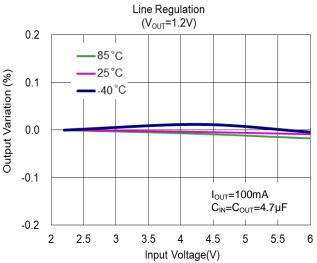


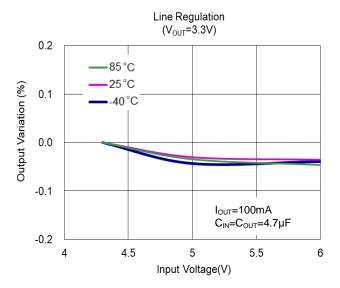




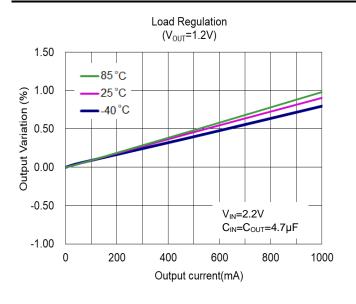


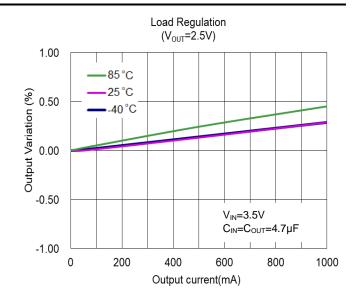


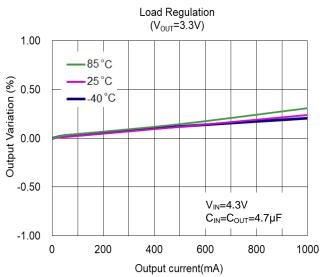


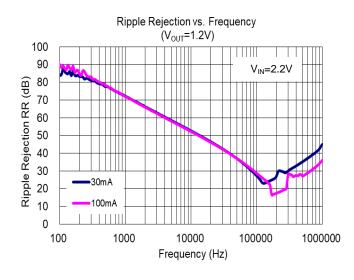


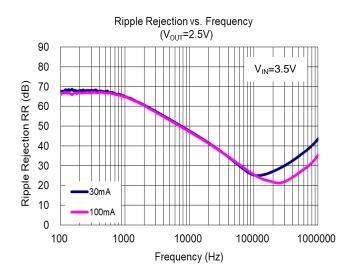


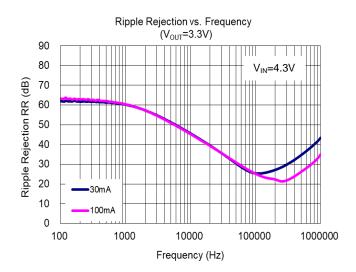














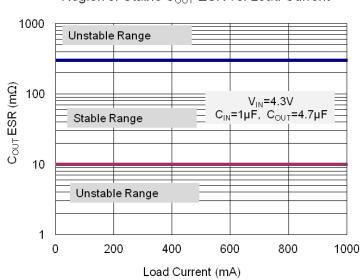
## **Application Information**

#### **Input Capacitor**

A 1µF ceramic capacitor is recommended between IN and GND pins to decouple input power supply glitch and noise. The amount of the capacitance may be increased without limit. This input capacitor must be located as close as possible to the device to assure input stability and reduce noise. For PCB layout, a wide copper trace is required for both IN and GND pins. A lower ESR capacitor type allows the use of less capacitance, while higher ESR type requires more capacitance.

#### **Output Capacitor**

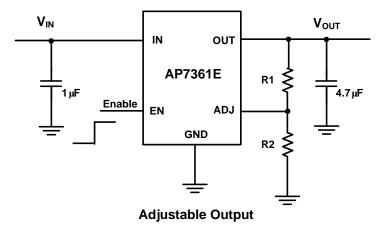
The output capacitor is required to stabilize and improve the transient response of the LDO. The AP7361E is stable with very small ceramic output capacitors. Using a ceramic capacitor value that is at least  $2.2\mu F$  with  $10m\Omega \le ESR \le 300m\Omega$  on the output ensures stability. Higher capacitance values help to improve line and load transient response. The output capacitance may be increased to keep low undershoot and overshoot. Output capacitor must be placed as close as possible to OUT and GND pins.



Region of Stable C<sub>OUT</sub> ESR vs. Load Current

#### **Adjustable Operation**

The AP7361E provides output voltage from 0.8V to 5.0V through external resistor divider as shown below.





### **Application Information** (continued)

The output voltage is calculated by:

$$V_{\text{OUT}} = V_{\text{REF}} \left( 1 + \frac{R_1}{R_2} \right)$$

Where VREF = 0.8V (the internal reference voltage).

Rearranging the equation will give the following that is used for adjusting the output to a particular voltage:

$$R1 = R2 \left( \frac{V_{OUT}}{V_{REF}} - 1 \right)$$

To maintain the stability of the internal reference voltage, R2 needs to be kept smaller than  $80k\Omega$ .

#### No Load Stability

Other than external resistor divider, no minimum load is required to keep the device stable. The device will remain stable and regulated in no load condition.

#### **ON/OFF Input Operation**

The AP7361E is turned on by setting the EN pin high, and is turned off by pulling it low. If this feature is not used, the EN pin should be tied to IN pin to keep the regulator output on at all time. To ensure proper operation, the signal source used to drive the EN pin must be able to swing above and below the specified turn-on/off voltage thresholds listed in the *Electrical Characteristics* section under V<sub>IL</sub> and V<sub>IH</sub>.

#### **Current Limit Protection**

When output current at OUT pin is higher than current limit threshold, the current limit protection will be triggered and clamp the output current to prevent over-current and to protect the regulator from damage due to overheating.

#### **Short Circuit Protection**

When OUT pin is short-circuit to GND, short circuit protection will be triggered and clamp the output current to approximately 400mA. Full current is restored when the output voltage exceeds 15% of Vout. This feature protects the regulator from over-current and damage due to overheating.

#### **Power Good**

The power-good (PG) pin is an open-drain output and can be pulled up through a resistor of  $10k\Omega$  to  $1M\Omega$  to  $V_{IN}$ ,  $V_{OUT}$  or any other rail that is 6V or lower. When the  $V_{OUT} \ge V_{PGR}$ , the PG output is high-impedance; if the  $V_{OUT}$  drops to below  $V_{PGF}$ , or the device is disabled, the PG pin is pulled to low by an internal MOSFET.

#### Thermal Shutdown Protection

Thermal protection disables the output when the junction temperature rises to approximately +150°C, allowing the device to cool down. When the junction temperature reduces to approximately +130°C the output circuitry is enabled again. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the heat dissipation of the regulator, protecting it from damage due to overheating.

### **Ultra Fast Start-up**

After enabled, the AP7361E is able to provide full power in as little as tens of microseconds, typically 200µs, without sacrificing low ground current. This feature will help load circuitry move in and out of standby mode in real time, eventually extend battery life for mobile phones and other portable devices.

#### Low Quiescent Current

The AP7361E, consuming only around 60µA for all input range, provides great power saving in portable and low power applications.



## Application Information (continued)

### **Power Dissipation**

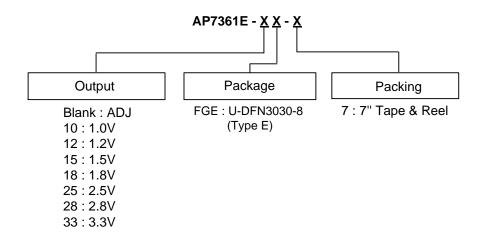
The device power dissipation and proper sizing of the thermal plane that is connected to the thermal pad is critical to avoid thermal shutdown and ensure reliable operation. Power dissipation of the device depends on input voltage and load conditions and can be calculated by:

The maximum power dissipation, handled by the device, depends on the maximum junction to ambient thermal resistance, maximum ambient temperature, and maximum device junction temperature, which can be calculated by the equation in the following:

$$P_{D}(\text{max@T}_{A}) = \frac{(+150^{\circ}\text{C} - \text{T}_{A})}{R_{\theta JA}}$$



## **Ordering Information**



Part Number	Packago Codo	Package Code Packaging 7" Tape and		d Reel	
Fait Nullibei	Fackage Code	Fackaging	Quantity	Part Number Suffix	
AP7361E-XFGE-7	FGE	U-DFN3030-8 (Type E)	3000/Tape & Reel	-7	

## **Marking Information**

(1) U-DFN3030-8 (Type E)

## (Top View)

XXX $\underline{Y} \underline{W} \underline{X}$ 

XXX: Identification Code

Y: Year: 0~9

<u>W</u>: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents

52 and 53 week X : Internal Code

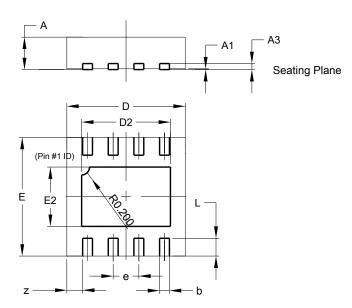
Part Number	Package	Identification Code
AP7361E-FGE-7	U-DFN3030-8 (Type E)	C9A
AP7361E-10FGE-7	U-DFN3030-8 (Type E)	C9B
AP7361E-12FGE-7	U-DFN3030-8 (Type E)	C9C
AP7361E-15FGE-7	U-DFN3030-8 (Type E)	C9D
AP7361E-18FGE-7	U-DFN3030-8 (Type E)	C9E
AP7361E-25FGE-7	U-DFN3030-8 (Type E)	C9F
AP7361E-28FGE-7	U-DFN3030-8 (Type E)	C9G
AP7361E-33FGE-7	U-DFN3030-8 (Type E)	C9H



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### U-DFN3030-8 (Type E)

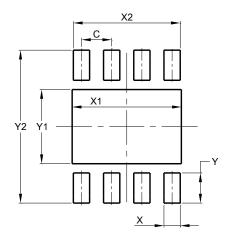


U-DFN3030-8				
		pe E)		
Dim	Min	Max	Тур	
Α	0.57	0.63	0.60	
<b>A</b> 1	0.00	0.05	0.02	
A3	-	-	0.15	
b	0.20	0.30	0.25	
D	2.95	3.05	3.00	
D2	2.15	2.35	2.25	
Е	2.95	3.05	3.00	
E2	1.40	1.60	1.50	
е	-	-	0.65	
L	0.30	0.60	0.45	
Z	-	-	0.40	
All Dimensions in mm				

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### U-DFN3030-8 (Type E)



Dimensions	Value (in mm)
С	0.650
Х	0.350
X1	2.350
X2	2.300
Y	0.650
Y1	1.600
Y2	3.300

## **Mechanical Data**

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu over Copper Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.0164 grams (Approximate)



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